

# CMS25N03V8-HF

N-Channel  
RoHS Device  
Halogen Free

## Features

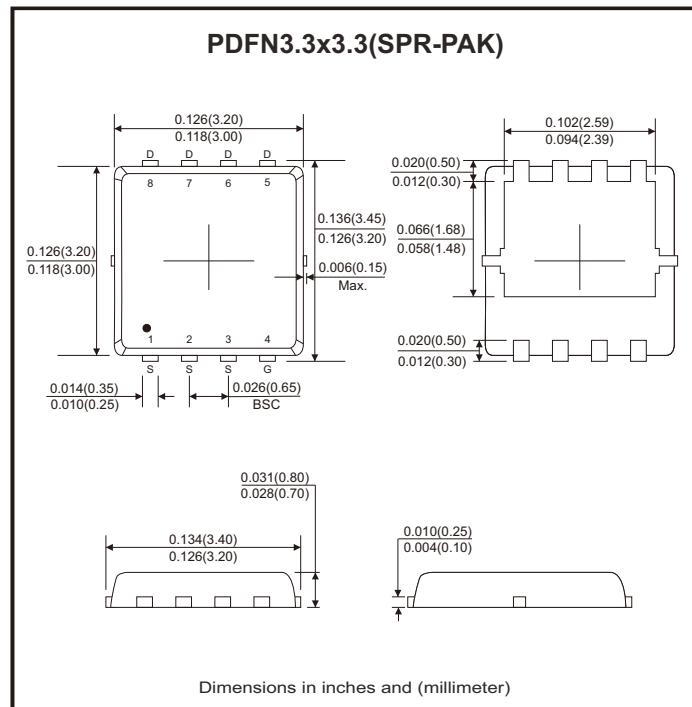
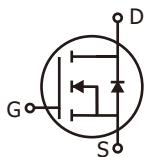
- Advanced high cell density trench technology.
- Super low gate charge.
- Excellent cdv/dt effect decline.
- Green device available.
- 100% EAS guaranteed.

## Mechanical data

- Case: PDFN3.3x3.3/SPR-PAK standard package, molded plastic.

## Circuit diagram

- G : Gate
- S : Source
- D : Drain



## Maximum Ratings

| Parameter  | Conditions                | Symbol          | Value       | Unit |
|--|---------------------------|-----------------|-------------|------|
| Drain-source voltage                               |                           | $V_{DS}$        | 30          | V    |
| Gate-source voltage                                |                           | $V_{GS}$        | $\pm 20$    | V    |
| Continuous drain current (Note 1)                  | $I_D @ T_c = 25^\circ C$  |                 | 25          | A    |
|  | $I_D @ T_c = 100^\circ C$ |                 | 16          |      |
| Pulsed drain current (Note 1, 2)                   |                           | $I_{DM}$        | 55          | A    |
| Total power dissipation (Note 4)                   | $P_D @ T_c = 25^\circ C$  |                 | 20          | W    |
|  | $P_D @ T_A = 25^\circ C$  |                 | 1.7         |      |
| Single pulse avalanche energy, $L=0.1mH$ (Note 3)  |                           | $E_{AS}$        | 22          | mJ   |
| Single pulse avalanche current, $L=0.1mH$ (Note 3) |                           | $I_{AS}$        | 21          | A    |
| Operating junction temperature range               |                           | $T_J$           | -55 to +150 | °C   |
| Storage temperature range                          |                           | $T_{STG}$       | -55 to +150 | °C   |
| Thermal resistance junction-ambient (Note 1)       | Steady state              | $R_{\theta JA}$ | 75          | °C/W |
| Thermal resistance junction-case (Note 1)          | Steady state              | $R_{\theta JC}$ | 6           | °C/W |

**Electrical Characteristics** (at  $T_J=25^\circ\text{C}$  unless otherwise noted)

| Parameter   | Symbol                   | Conditions   | Min | Typ  | Max       | Unit             |
|---|--------------------------|--|-----|------|-----------|------------------|
| Drain-source breakdown voltage                          | $\text{BV}_{\text{DSS}}$ | $V_{\text{GS}} = 0\text{V}, I_{\text{D}} = 250\mu\text{A}$   | 30  |      |           | V                |
| Gate threshold voltage                                  | $V_{\text{GS(th)}}$      | $V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = 250\mu\text{A}$   | 1.0 | 1.8  | 2.5       |                  |
| Gate-source leakage current                             | $I_{\text{GSS}}$         | $V_{\text{GS}} = \pm 20\text{V}$   |     |      | $\pm 100$ | nA               |
| Drain-source leakage current ( $T_J=25^\circ\text{C}$ ) | $I_{\text{DSS}}$         | $V_{\text{DS}} = 30\text{V}, V_{\text{GS}} = 0\text{V}$  |     |      | 1         | $\mu\text{A}$    |
| Drain-source leakage current ( $T_J=55^\circ\text{C}$ ) |                          | $V_{\text{DS}} = 24\text{V}, V_{\text{GS}} = 0\text{V}$  |     |      | 5         |                  |
| Static drain-source on-resistance (Note 2)              | $R_{\text{DS(on)}}$      | $V_{\text{GS}} = 10\text{V}, I_{\text{D}} = 10\text{A}$  |     | 15   | 18        | $\text{m}\Omega$ |
|   |                          | $V_{\text{GS}} = 4.5\text{V}, I_{\text{D}} = 5\text{A}$  |     | 21   | 28        |                  |
| Total gate charge (Note 2)                              | $Q_g$                    | $I_{\text{D}} = 10\text{A}, V_{\text{DS}} = 20\text{V}, V_{\text{GS}} = 4.5\text{V}$                             |     | 7.2  |           | $\text{nC}$      |
| Gate-source charge                                      | $Q_{\text{gs}}$          |  |     | 1.4  |           |                  |
| Gate-drain ("miller") charge                            | $Q_{\text{gd}}$          |  |     | 2.2  |           |                  |
| Turn-on delay time (Note 2)                             | $t_{\text{d(on)}}$       | $V_{\text{DS}} = 12\text{V}, V_{\text{GS}} = 10\text{V}$<br>$I_{\text{D}} = 5\text{A}, R_{\text{G}} = 3.3\Omega$ |     | 4.1  |           | $\text{nS}$      |
| Rise time   | $t_r$                    |  |     | 9.8  |           |                  |
| Turn-off delay time                                     | $t_{\text{d(off)}}$      |  |     | 15.5 |           |                  |
| Fall time   | $t_f$                    |  |     | 6.0  |           |                  |
| Input capacitance                                       | $C_{\text{iss}}$         | $V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 15\text{V}, f = 1\text{MHz}$   |     | 572  |           | $\text{pF}$      |
| Output capacitance                                      | $C_{\text{oss}}$         |  |     | 81   |           |                  |
| Reverse transfer capacitance                            | $C_{\text{rss}}$         |  |     | 65   |           |                  |
| Gate resistance   | $R_g$                    | $f = 1\text{MHz}$  |     | 2.5  |           | $\Omega$         |
| <b>Source-drain diode</b>                               |                          |  |     |      |           |                  |
| Diode forward voltage (Note 2)                          | $V_{\text{SD}}$          | $I_{\text{S}} = 10\text{A}, V_{\text{GS}} = 0\text{V}, T_J=25^\circ\text{C}$                                     |     |      | 1.2       | V                |
| Continuous source current (Note 1,6)                    | $I_{\text{S}}$           | $V_G = V_D = 0\text{V}$ , Force current  |     |      | 25        | A                |
| Pulsed source current (Note 2,6)                        | $I_{\text{SM}}$          |  |     |      | 50        | A                |
| <b>Guaranteed avalanche characteristics</b>             |                          |  |     |      |           |                  |
| Single pulse avalanche energy (Note 5)                  | EAS                      | $V_{\text{DD}} = 25\text{V}, L=0.1\text{mH}, I_{\text{AS}} = 10\text{A}$   | 5   |      |           | mJ               |

- Notes:
1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2 oz copper.
  2. The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
  3. The EAS data shows max. rating. The test condition is  $V_{\text{DD}}=25\text{V}$ ,  $V_{\text{GS}}=10\text{V}$ ,  $L=0.1\text{mH}$ ,  $I_{\text{AS}}=21\text{A}$ .
  4. The power dissipation is limited by  $150^\circ\text{C}$  junction temperature.
  5. The min. value is 100% EAS tested guarantee.
  6. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

## Rating and Characteristic Curves (CMS25N03V8-HF)

Fig.1 - Typical Output Characteristics

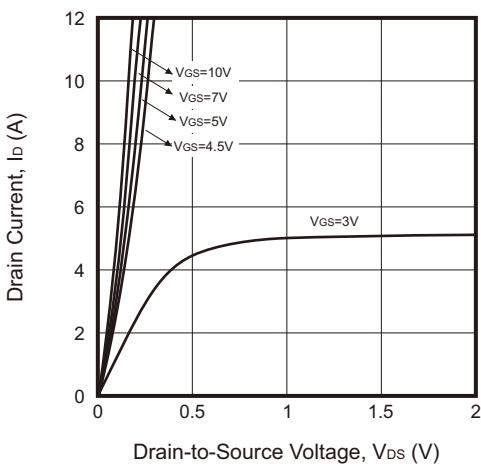


Fig.2 - On-Resistance vs. G-S Voltage

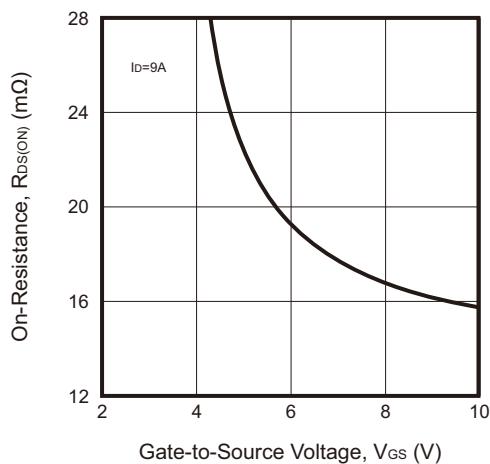


Fig.3 - Normalized  $V_{GS(th)}$  vs.  $T_J$

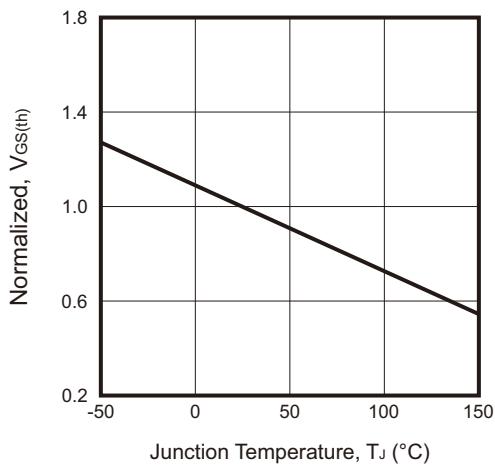


Fig.4 - Normalized  $R_{DS(ON)}$  vs.  $T_J$

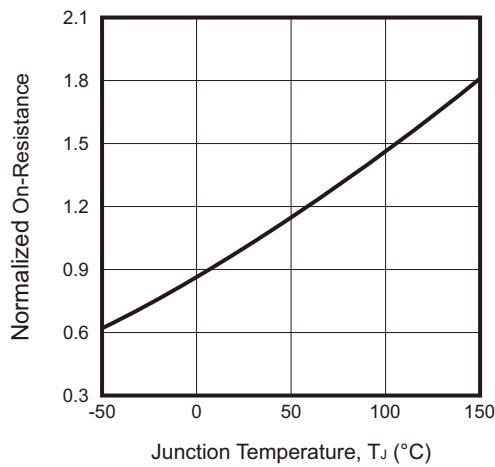


Fig.5 - Safe Operating Area

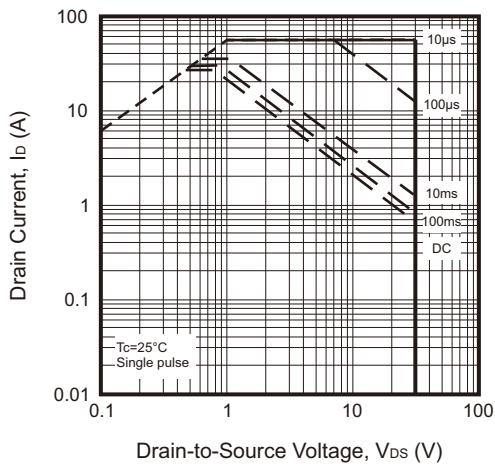
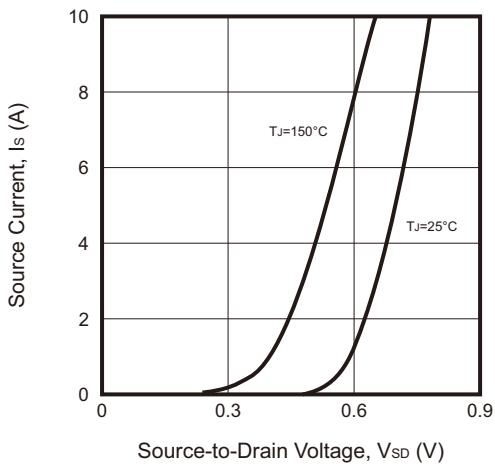


Fig.6 - Forward Characteristics of Reverse



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## Rating and Characteristic Curves (CMS25N03V8-HF)

Fig.7 - Gate Charge Characteristics

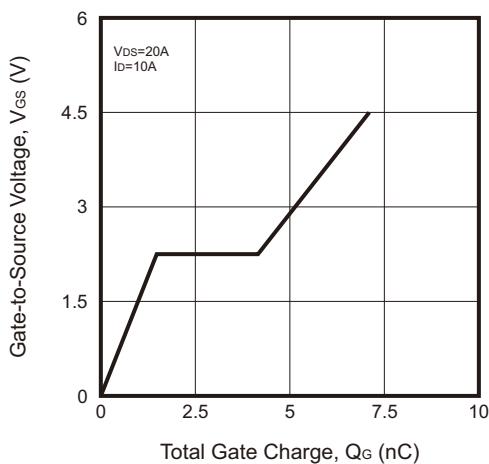
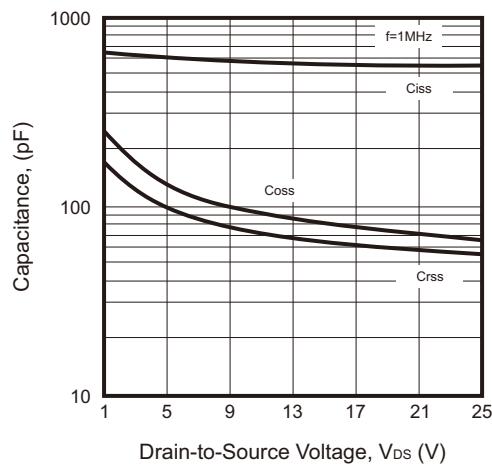
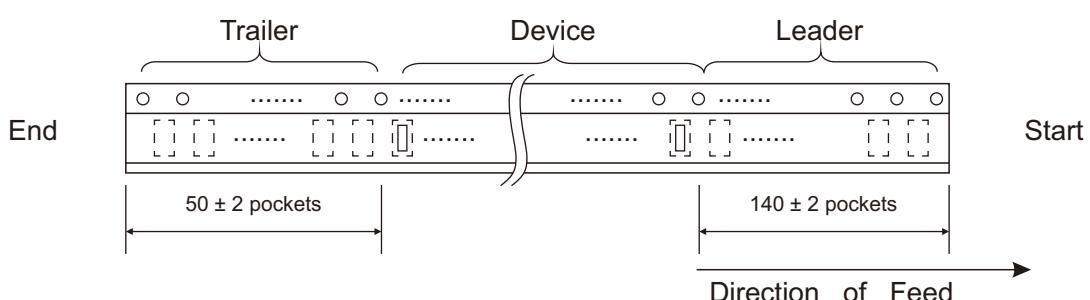
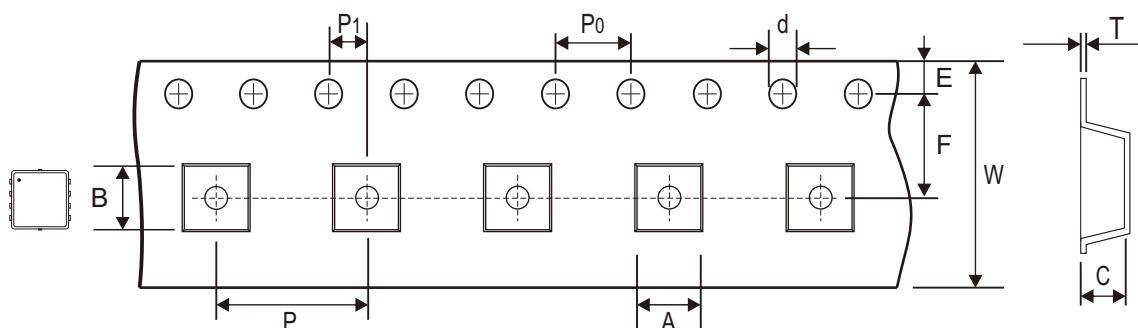


Fig.8 - Capacitance Characteristics



## Reel Taping Specification



| SPR-PAK | SYMBOL | A                 | B                 | C                          | d                          | D                  | D1                         | D2         |
|---------|--------|-------------------|-------------------|----------------------------|----------------------------|--------------------|----------------------------|------------|
|         | (mm)   | $3.55 \pm 0.10$   | $3.55 \pm 0.10$   | $1.10 + 0.10$<br>- 0.05    | $1.50 + 0.10$<br>- 0.00    | $330.00 \pm 1.00$  | $178.00 + 0.00$<br>- 2.00  | 13.00 min. |
|         | (inch) | $0.140 \pm 0.004$ | $0.140 \pm 0.004$ | $0.043 + 0.004$<br>- 0.002 | $0.059 + 0.004$<br>- 0.000 | $12.992 \pm 0.039$ | $7.008 + 0.000$<br>- 0.079 | 0.512 min. |

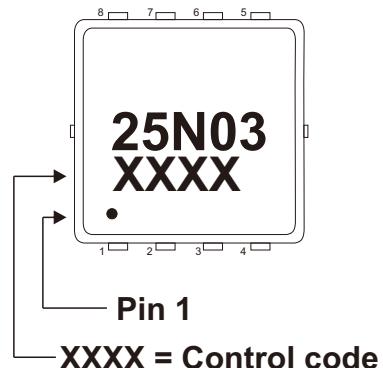
| SPR-PAK | SYMBOL | E                 | F                 | P                 | P0                | P1                | T                 | W                          | W1         |
|---------|--------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|----------------------------|------------|
|         | (mm)   | $1.75 \pm 0.10$   | $5.50 \pm 0.05$   | $8.00 \pm 0.10$   | $4.00 \pm 0.10$   | $2.00 \pm 0.05$   | $0.30 \pm 0.05$   | $12.00 + 0.30$<br>- 0.10   | 18.40 ref. |
|         | (inch) | $0.069 \pm 0.004$ | $0.217 \pm 0.002$ | $0.315 \pm 0.004$ | $0.157 \pm 0.004$ | $0.079 \pm 0.002$ | $0.012 \pm 0.002$ | $0.472 + 0.012$<br>- 0.004 | 0.724 ref. |

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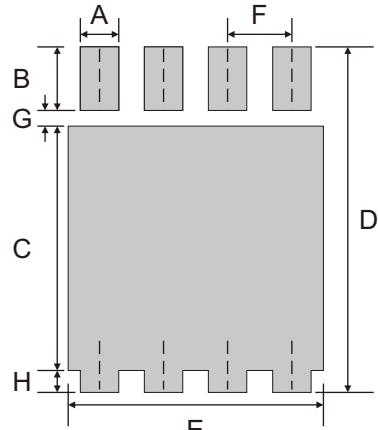
## Marking Code

| Part Number   | Marking Code |
|---------------|--------------|
| CMS25N03V8-HF | 25N03        |



## Suggested PAD Layout

| SIZE | SPR-PAK<br>(PDFN3.3x3.3) |        |
|------|--------------------------|--------|
|      | (mm)                     | (inch) |
| A    | 0.40                     | 0.016  |
| B    | 0.60                     | 0.024  |
| C    | 2.35                     | 0.093  |
| D    | 3.55                     | 0.140  |
| E    | 2.80                     | 0.110  |
| F    | 0.65                     | 0.026  |
| G    | 0.35                     | 0.014  |
| H    | 0.25                     | 0.010  |



Note: 1. The pad layout is for reference purposes only.

## Standard Packaging

| Case Type                | REEL PACK       |                     |
|--------------------------|-----------------|---------------------|
|                          | REEL<br>( pcs ) | Reel Size<br>(inch) |
| SPR-PAK<br>(PDFN3.3x3.3) | 3000            | 13                  |